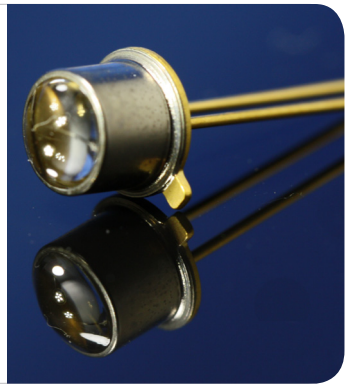
Marktech Optoelectronics

Infrared Emitter

Product No: **MTE8800N**

Peak Emission Wavelength: 880nm

The 880nm IR emitter series is designed for applications requiring high output and precise optical / mechanical axis alignment. Custom package solutions and sorting are available.



FEATURES

> TO-18 Metal Can Domed Package
> High Output Power
> Narrow Beam Angle
> High Reliability

APPLICATIONS

> Optical Switches / Security Systems
> Linear & Rotary Encoder
> Remote Controls / Robotics
> Card Readers / Medical Electronics

Absolute Maximum Ratings (Ta=25°C)

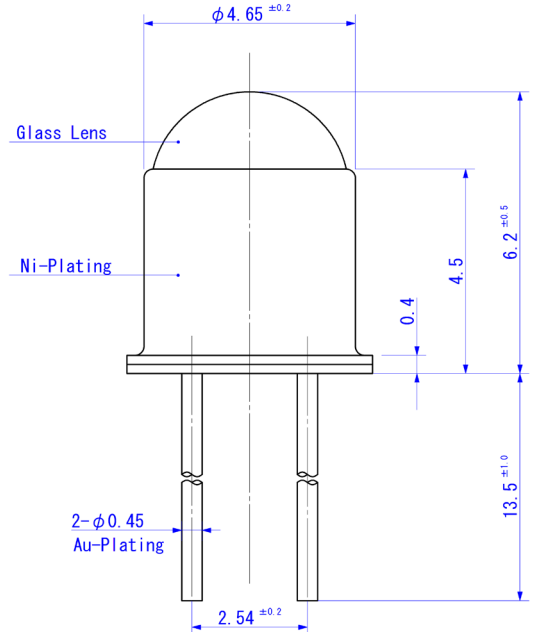
ITEMS	SYMBOL	RATINGS	UNIT
Forward Current (DC)	IF	100	mA
Forward Current (Pulse)*1	IFP	1	A
Reverse Voltage	VR	5	V
Power Dissipation	PD	180	mW
Operating Temperature Range	Topr	-20 ~ +85	°C
Storage Temperature Range	Tstg	-30 ~ +100	°C
Junction Temperature	Tj	100	°C
Lead Soldering Temperature*2	Tls	260	°C

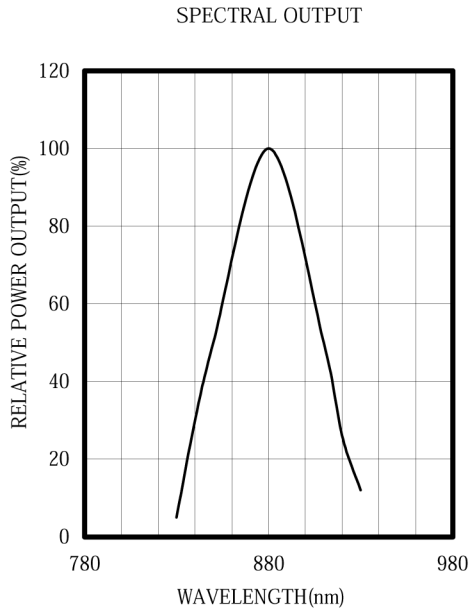
*1: Tw=10µsec, T=10msec. *2: Time 5 Sec max, Position: Up to 3mm from the body.

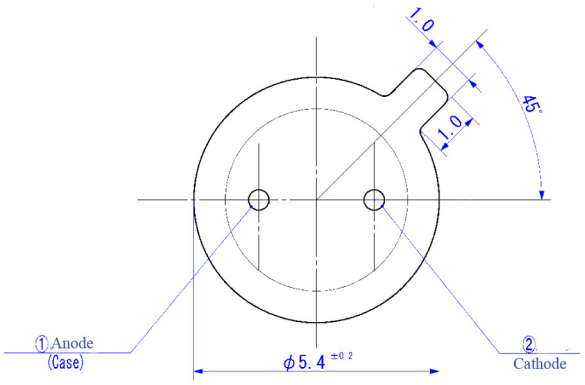
Electrical & Optical Characteristics (Ta = 25°C)

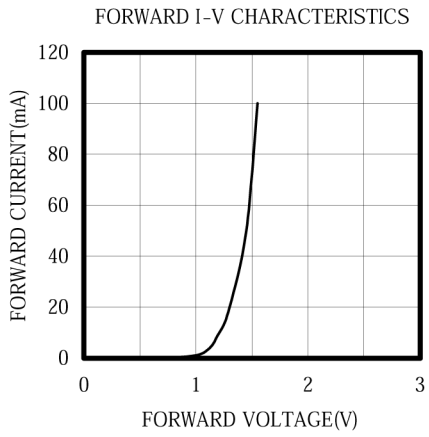
ITEMS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Power Output	PO	IF=50mA	--	6.0	--	mW
Forward Voltage	VF	IF=50mA	--	1.45	1.8	V
Reverse Current	IR	VR=5V	--	--	10	µA
Peak Emission Wavelength	λp	IF=50mA	--	880	--	nm
Spectral Line Half Width	Δλ	IF=50mA	--	60	--	nm
Half Intensity Beam Angle	Θ	IF=50mA	--	±6	--	deg
Rise Time	Tr	IFP=50mA	--	1.5	--	µS
Fall TIme	Tf	IFP=50mA	--	0.8	--	µS
Junction Capacitance	Cj	1MHz, V=0V	--	15	--	pF
Temperature Coefficient of PO	P/T	IF=10mA	--	-0.5	--	%/°C
Temperature Coefficient of VF	V/T	IF=10mA	--	-1.5	--	mV/°C

2011-07-28





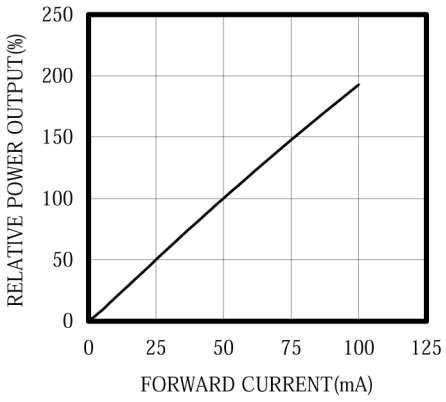




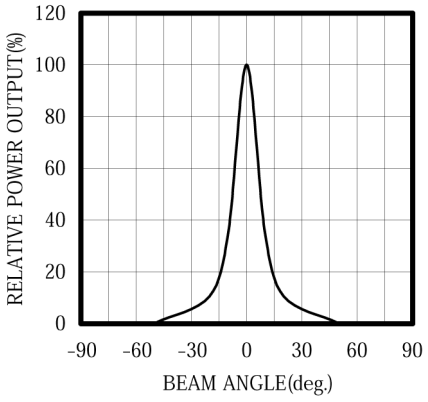
Unit: mm, Tolerance: ±0.2

2011-07-28

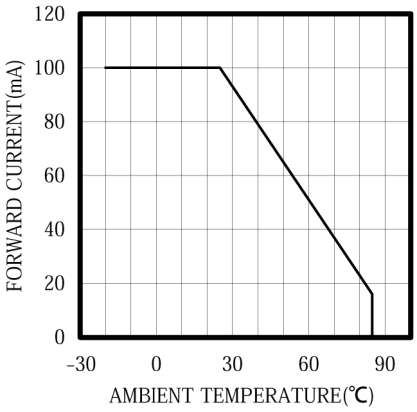
RELATIVE POWER vs FORWARD CURRENT



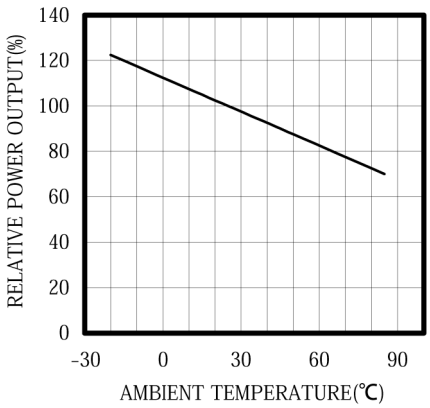
RADIATION PATTERN



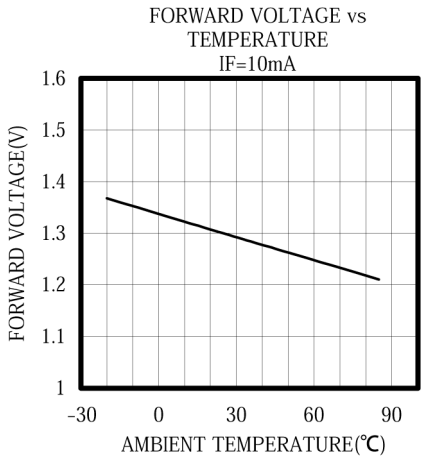
THERMAL DERATING CURVE



POWER OUTPUT vs TEMPERATURE
IF=10mA



2011-07-28



The information contained herein is subject to change without notice.

2011-07-28